

SIT612

Photo Interrupter

Dimensions

(Unit: mm)

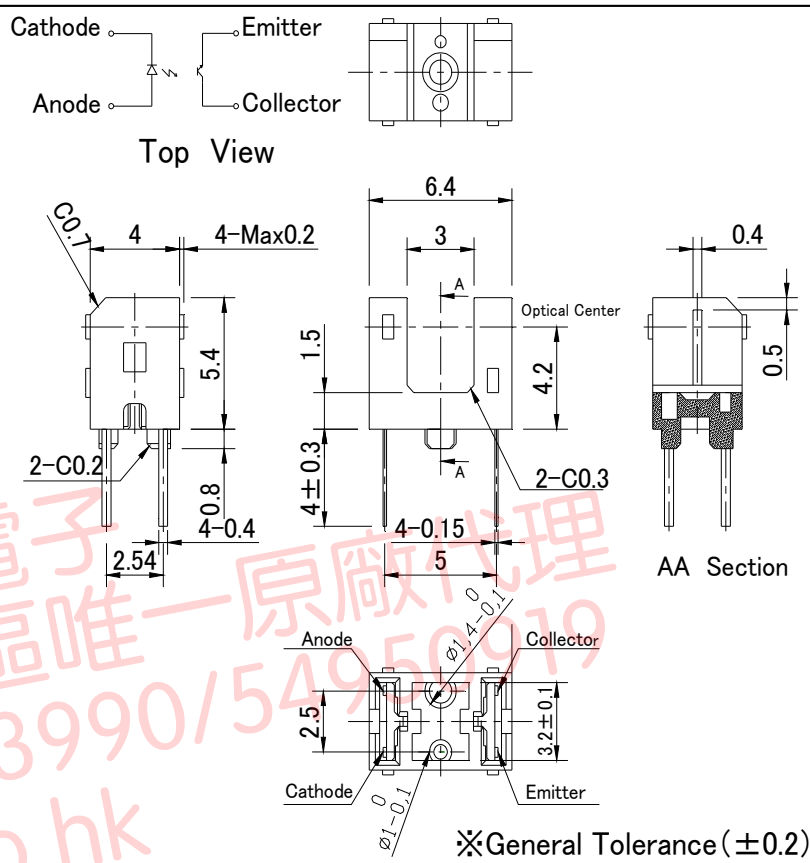
The SIT612 is a photointerrupter high-performance standard type, combines high-output GaAs IRED with high sensitive phototransistor

Features

- PWB direct mount type
- GAP:3.0mm
- With the installation positioning boss
- Compact/ Low cost

Applications

- Printer
- VTR
- Cassette mecha
- Car stereo



Maximum Ratings

($T_a=25^{\circ}\text{C}$)

Item		Symbol	Rating	Unit
Input	Power dissipation	P_D	75	mW
	Forward current	I_F	50	mA
	Reverse voltage	V_R	5	V
Output	Collector power dissipation	P_C	75	mW
	Collector current	I_C	20	mA
	Collector-Emitter voltage	V_{CEO}	30	V
	Emitter-Collector voltage	V_{ECO}	5	V
Operating temperature		Topr.	-20 ~ +85	°C
Storage temperature * ¹		Tstg.	-30 ~ +85	°C
Soldering temperature * ²		Tsol.	260	°C

*1. No icebound or dew.

*2. The soldering should be 1.2mm away from bottom of the holder t=within 5s

Elector-Optical Characteristics

(Ta=25℃)

Item		Symbol	Conditions	Min.	Typ.	Max.	Unit
Input	Forward voltage	V_F	$I_F=20\text{mA}$	-	1.2	1.4	V
	Reverse current	I_R	$V_R=5\text{V}$	-	-	10	μA
	Peak wavelength	λ_P	$I_F=20\text{mA}$	-	940	-	nm
Output	Dark current	I_{CEO}	$V_{CE}=10\text{V}$ $E_V=0\text{ lx}$	-	1	100	nA
	Peak SENS.Wavelength	λ_P	-	-	880	-	nm
Transfer characteristics	Light current	I_{CEL}	$I_F=20\text{mA}$ $V_{CE}=5\text{V}$ 入光状态 (Non-Shading)	0.2	-	4.5	mA
	Leak current	I_{CEOD}	$I_F=20\text{mA}$ $V_{CE}=5\text{V}$ 遮光状态 (Shading)	-	0.5	10	μA
	C-E sat.voltage	$V_{CE(sat)}$	$I_F=20\text{mA}$ $I_C=0.05\text{mA}$	-	0.15	0.4	V
	Rise time	t_r	$I_C=0.1\text{mA}$ $V_{CC}=5\text{V}$ $R_L=1\text{K}\Omega$	-	50	-	μs
	Fall time	t_f		-	50	-	μs

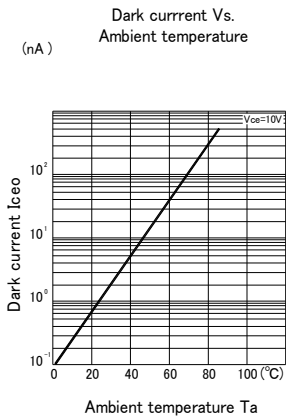
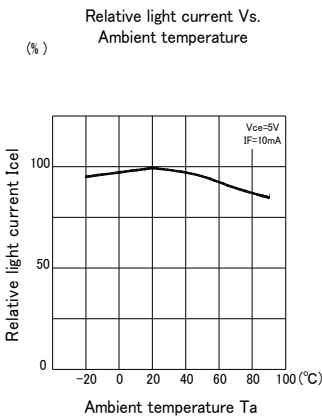
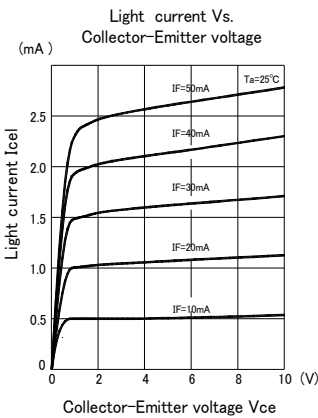
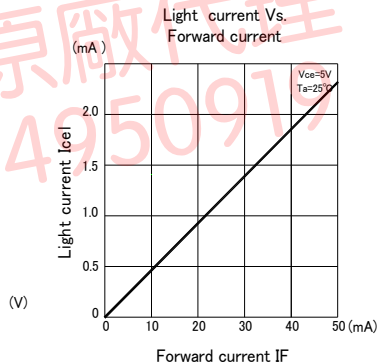
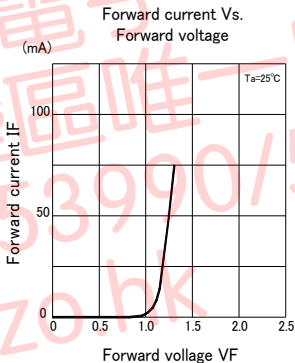
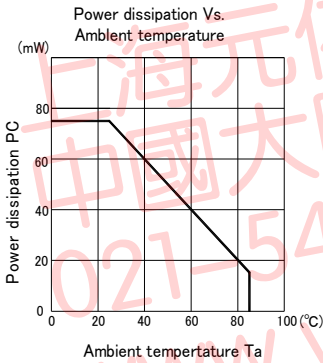


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